

# Chip tantalum capacitors

## TCT Series P Case

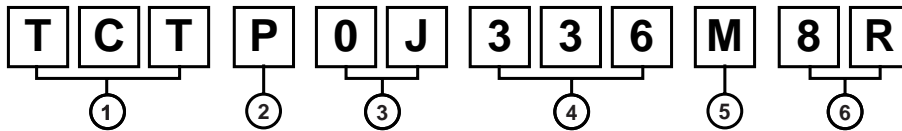
●Features (P)

- 1) Vital for all hybrid integrated circuits board application.
- 2) Wide capacitance range.
- 3) Screening by thermal shock.

●Dimensions (Unit : mm)

(Unit : mm)	
Dimensions	Size
L	2.0±0.2
W <sub>1</sub>	1.25±0.2
W <sub>2</sub>	0.85±0.2
H	1.1±0.1
S	0.5±0.1

●Part No. Explanation



① Series name  
TCT

② Case style  
TC.....P

③ Rated voltage

Rated voltage (V)	2.5	4	6.3	10	16	20	25
CODE	0E	0G	0J	1A	1C	1D	1E

④ Nominal capacitance  
Nominal capacitance in pF in 3 digits:  
2 significant figures followed by the figure representing the number of 0's.

⑤ Capacitance tolerance  
M : ±20%

⑥ Taping  
8 : Tape width  
R : Positive electrode on the side opposite to sprocket hole

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● Rated table

(μF)	Rated voltage (V)						
	2.5 0E	4 0G	6.3 0J	10 1A	16 1C	20 1D	25 1E
2.2 (225)							<b>New</b> P
3.3 (335)							*P
4.7 (475)					*P		
6.8 (685)							
10 (106)					P		
15 (156)				P			
22 (226)			P	P			
33 (336)		P	P	<b>New</b> P			
47 (476)		P	P				
68 (686)		<b>New</b> P	*P				
100 (107)	<b>New</b> P	<b>New</b> P					
150 (157)	*P	*P					
220 (227)	*P						

Remark) Case size codes (P) in the above show products line-up.

\* Under development

**New** New Product

● Marking

The indications listed below should be given on the surface of a capacitor.

- (1) Polarity : The polarity should be shown by □ bar. (on the anode side)
- (2) Rated DC voltage : Due to the small size of P case, a voltage code is used as shown below.
- (3) Visual typical example (1) voltage code (2) capacitance code

Voltage Code	Rated DC Voltage (V)
e	2.5
g	4
j	6.3
A	10
C	16
D	20
E	25

Capacitance Code	Nominal Capacitance (μF)
A	1.0
E	1.5
J	2.2
N	3.3
S	4.7
W	6.8
a	10
e	15
j	22
n	33
s	47
w	68
ā	100
ē	150
j̄	220

[P case] note 1)  $\frac{j}{(1)} \frac{n}{(2)}$



note 2) voltage code and capacitance code are variable with parts number

## Tantalum capacitors

## ● Characteristics

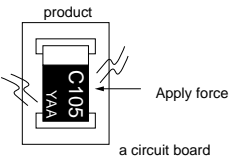
Item		Performance	Test conditions (based on JIS C 5101-1 and JIS C 5101-3)															
Operating Temperature		-55°C to +125°C	Voltage reduction when temperature exceeds +85°C															
Maximum operating temperature with no voltage derating		+85°C																
Rated voltage (VDC)		2.5 4 6.3 10 16 20 25	at 85°C															
Category voltage (VDC)		1.6 2.5 4 6.3 10 13 16	at 125°C															
Surge voltage (VDC)		3.2 5.0 8 13 20 26 32	at 85°C															
DC Leakage current		Shown in " Standard list "	As per 4.9 JIS C 5101-1 As per 4.5.1 JIS C 5101-3 Voltage : Rated voltage for 5min															
Capacitance tolerance		Shall be satisfied allowance range. ±20%	As per 4.7 JIS C 5101-1 As per 4.5.2 JIS C 5101-3 Measuring frequency : 120±12Hz Measuring voltage : 0.5Vrms +1.5 to 2V.DC Measuring circuit : DC Equivalent series circuit															
Tangent of loss angle (Df, tan δ)		Shall be satisfied the voltage on " Standard list "	As per 4.8 JIS C 5101-1 As per 4.5.3 JIS C 5101-3 Measuring frequency : 120±12Hz Measuring voltage : 0.5Vrms +1.5 to 2V.DC Measuring circuit : DC Equivalent series circuit															
Impedance		Shall be satisfied the voltage on " Standard list "	As per 4.10 JIS C 5101-1 As per 4.5.4 JIS C 5101-3 Measuring frequency : 100±10kHz Measuring voltage : 0.5Vrms or less Measuring circuit : DC Equivalent series circuit															
Resistance to Soldering heat	Appearance	There should be no significant abnormality. The indications should be clear.	As per 4.14 JIS C 5101-1 As per 4.6 JIS C 5101-3 Dip in the solder bath Solder temp : 260±5°C Duration : 5±0.5s Repetition : 1 After the specimens, leave it at room temperature for over 24h and then measure the sample.															
	L.C.	Less than initial limit																
	ΔC / C	Within ±20% of initial value																
	Df (tan δ)	Less than 200% of initial limit																
Temperature cycle	Appearance	There should be no significant abnormality. The indications should be clear.	As per 4.16 JIS C 5101-1 As per 4.10 JIS C 5101-3 Repetition : 5 cycles (1 cycle : steps 1 to 4) without discontinuation.															
	L.C.	Less than 200% of initial limit																
	ΔC / C	Within ±20% of initial value																
	Df (tan δ)	Less than 200% of initial limit																
			<table border="1"> <thead> <tr> <th></th> <th>Temp.</th> <th>Time</th> </tr> </thead> <tbody> <tr> <td>1</td> <td>-55±3°C</td> <td>30±3min.</td> </tr> <tr> <td>2</td> <td>Room temp.</td> <td>3min. or less</td> </tr> <tr> <td>3</td> <td>125±2°C</td> <td>30±3min.</td> </tr> <tr> <td>4</td> <td>Room temp.</td> <td>3min. or less</td> </tr> </tbody> </table>		Temp.	Time	1	-55±3°C	30±3min.	2	Room temp.	3min. or less	3	125±2°C	30±3min.	4	Room temp.	3min. or less
	Temp.	Time																
1	-55±3°C	30±3min.																
2	Room temp.	3min. or less																
3	125±2°C	30±3min.																
4	Room temp.	3min. or less																
Moisture resistance	Appearance	There should be no significant abnormality. The indications should be clear.	As per 4.22 JIS C 5101-1 As per 4.12 JIS C 5101-3 After leaving the sample under such atmospheric condition that the temperature and humidity are 60±2°C and 90 to 95% RH, respectively, for 500±12h leave it at room temperature for over 24h and then measure the sample.															
	L.C.	Less than 200% of initial limit																
	ΔC / C	Within ±20% of initial value																
	Df (tan δ)	Less than 200% of initial limit																

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項目	性能		試験条件 ( JIS C 5101-1, JIS C 5101-3に準拠 )
温度特性	温度	温度 -55°C	JIS C 5101-1 4.29項 JIS C 5101-3 4.13項
	ΔC / C	試験前の値に対し0/-15%以内	
	tan	「標準品一覧」に記載の値以下	
	L.C.	-	
	温度	温度 +85°C	
	ΔC / C	試験前の値に対し+15/0%以内	
	tan	「標準品一覧」に記載の値以下	
	L.C.	POG107 : 0.5CV値以下 POJ476 : 0.5CV値以下 その他 : 5μA又は0.1CVの いずれか大きい方の値以下	
	温度	温度 +125°C	
	ΔC / C	試験前の値に対し+20/0%以内	
	L.C.	POG107 : 0.625CV値以下 POJ476 : 0.625CV値以下 その他 : 6.3μA又は0.125CVのいずれか 大きい方の値以下	
	耐サージ電圧	外観	
L.C.		初期規格値の2.0倍以下	
ΔC / C		試験前の値に対し±20%以内	
tan		初期規格値の2.0倍以下	
高温負荷	外観	著しい異常がなく、表示は容易に判読できること	JIS C 5101-1 4.23項 JIS C 5101-3 4.15項 温度85±2°Cの中で直列抵抗3Ω以下を通じて定格電圧を1000+36/0時間連続印加後、常温常湿中に24時間以上放置し測定する。
	L.C.	初期規格値の2.0倍以下	
	ΔC / C	試験前の値に対し±20%以内	
	tan	初期規格値の2.0倍以下	
端子強度	静電容量	測定中に、測定値が安定していること	JIS C 5101-1 4.35項 JIS C 5101-3 4.9項 曲がり半径が1mmに達するまでの規定の治具で加圧し、そのまま5秒間保持する。(下図参照)
	外観	著しい異常がないこと	
固着性	端子の剥離がないこと		JIS C 5101-1 4.34項 JIS C 5101-3 4.8項 基板実装後下図の2方向に5Nの力を10±1秒間加える 

# TCT Series P Case

## Tantalum capacitors

Item	Performance	Test conditions (JIS C 5101-1 and JIS C 5101-3)
Adhesiveness	The terminal should not come off.	As per 4.34 JIS C 5101-1 As per 4.8 JIS C 5101-3 Apply force of 5N in the two directions shown in the figure below for 10±1s after mounting the terminal on a circuit board. 
Dimensions	Refer to "External dimensions"	Measure using a caliper of JIS B 7507 Class 2 or higher grade.
Resistance to solvents	The indication should be clear	As per 4.32 JIS C 5101-1 As per 4.18 JIS C 5101-3 Dip in the isopropyl alcohol for 30±5s, at room temperature.
Solderability	3/4 or more surface area of the solder coated terminal dipped in the soldering bath should be covered with the new solder.	As per 4.15.2 JIS C 5101-1 As per 4.7 JIS C 5101-3 Dip speed=25±2.5mm / s Pre-treatment(accelerated aging): Leave the sample on the boiling distilled water for 1 h. Solder temp. : 245±5°C Duration : 3±0.5s Solder : M705 Flux : Rosin 25% IPA 75%
Vibration	Capacitance	Measure value should not fluctuate during the measurement.
	Appearance	There should be no significant abnormality.
		As per 4.17 JIS C 5101-1 Frequency : 10 to 55 to 10Hz/min. Amplitude : 1.5mm Time : 2h each in X and Y directions Mounting : The terminal is soldered on a print circuit board.

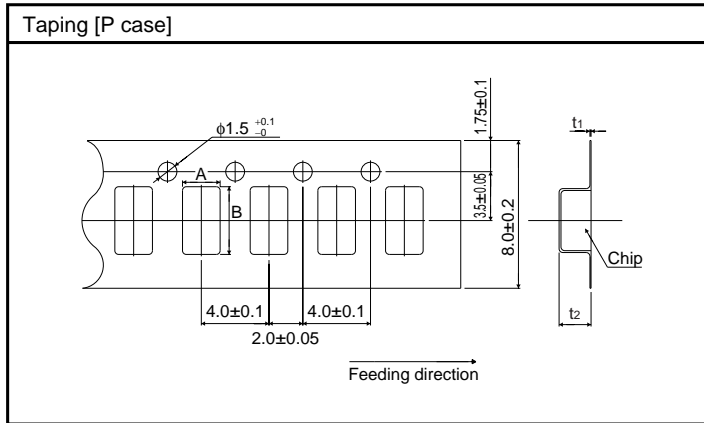
### ● Standard products list, TCT series P case

Part No.	Rated voltage 85°C (V)	Category voltage 125°C (V)	Surge voltage 85°C (V)	Cap. 120Hz (μF)	Tolerance (%)	Leakage current 25°C 1WV.60s (μA)	Df 120Hz (%)			Impedance 100kHz (Ω)
							-55°C	25°C 85°C	125°C	
TCT P 0E 107M8R	2.5	1.6	3.2	100	±20	12.5	60	30	40	4.0
TCT P 0G 107M8R	4	2.5	5	100	±20	20	60	30	40	4.0
TCT P 0G 336M8R	4	2.5	5	33	±20	1.3	30	20	30	4.0
TCT P 0G 476M8R	4	2.5	5	47	±20	1.9	30	20	30	4.0
TCT P 0G 686M8R	4	2.5	5	68	±20	13.6	60	30	40	4.0
TCT P 0J 226M8R	6.3	4	8	22	±20	1.4	30	20	30	5.0
TCT P 0J 336M8R	6.3	4	8	33	±20	2.1	30	20	30	4.0
TCT P 0J 476M8R	6.3	4	8	47	±20	14.8	60	30	40	4.0
TCT P 1A 156M8R	10	6.3	13	15	±20	1.5	30	20	30	6.0
TCT P 1A 226M8R	10	6.3	13	22	±20	2.2	30	20	30	5.0
TCT P 1A 336M8R	10	6.3	13	33	±20	16.5	60	30	40	4.0
TCT P 1C 106M8R	16	10	20	10	±20	1.6	30	20	30	6.0
TCT P 1E 225M8R	25	16	32	2.2	±20	0.55	30	20	30	8.0

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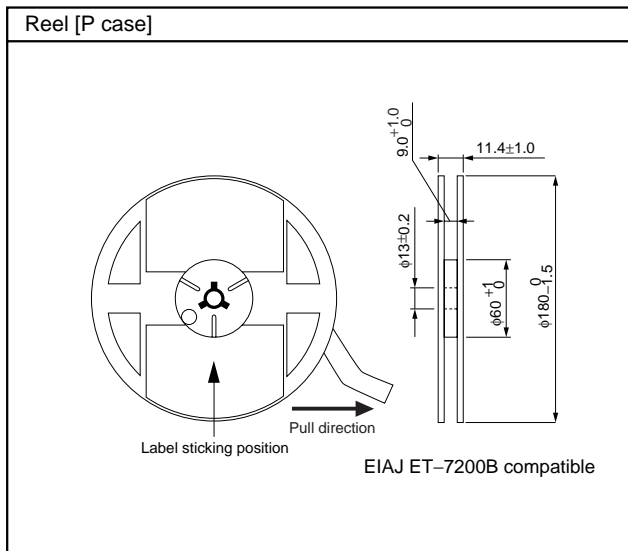
● Packaging specifications

Case code	A±0.1	B±0.1	t <sub>1</sub> ±0.05	t <sub>2</sub> ±0.1
P	1.55	2.3	0.25	1.5



● Packaging style

Case code	Packaging	Packaging style		Symbol	Basic ordering units
P case	Taping	plastic taping	$\phi$ 180mm Reel	R	3,000pcs



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●Recommended condition of reflow soldering

(1) Leakage current-to-voltage ratio

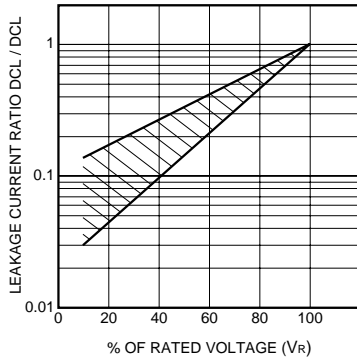


Fig.1

(2) Derating voltage as function of temperature

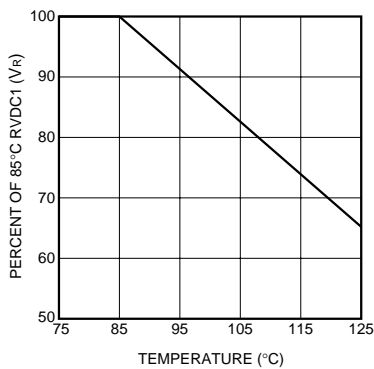


Fig.2

85°C		125°C	
Rated Voltage (V.DC)	Surge Voltage (V.DC)	Category Voltage (V.DC)	Surge Voltage (V.DC)
2.5	3.2	1.6	2.0
4	5.2	2.5	3.2
6.3	8	4	5
10	13	6.3	8
16	20	10	13
20	26	13	16
25	32	16	20

(3) Reliability

The malfunction rate of tantalum solid state electrolytic capacitors varies considerably depending on the conditions of usage (ambient temperature, applied voltage, circuit resistance).

Formula for calculating malfunction rate

$$\lambda_p = \lambda_b \times (\pi_E \times \pi_{SR} \times \pi_Q \times \pi_{CV})$$

- $\lambda_p$  : Malfunction rate stemming from operation
- $\lambda_b$  : Basic malfunction rate
- $\pi_E$  : Environmental factors
- $\pi_{SR}$  : Series resistance
- $\pi_Q$  : Level of malfunction rate
- $\pi_{CV}$  : Capacitance

For details on how to calculate the malfunction rate stemming from operation, see the tantalum solid state electrolytic capacitors column in MIL-HDBK-217.

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Malfunction rate as function of operating temperature and rated voltage

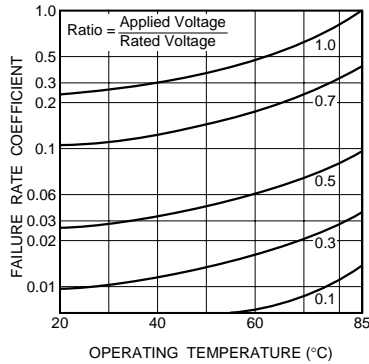


Fig.3

Malfunction rate as function of circuit resistance ( $\Omega/V$ )

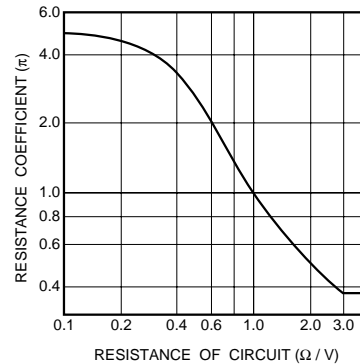


Fig.4

(4) Maximum power dissipation

Warming of the capacitor due to ripple voltage balances with warming caused by Joule heating and by radiated heat. Maximum allowable warming of the capacitor is to 5°C above ambient temperature. When warming exceeds 5°C, it can damage the dielectric and cause a short circuit.

Power dissipation (P) =  $I^2 \cdot R$

Ripple current

P : As shown in table at right

R : Equivalent series resistance

Notes:

1. Please be aware that when case size is changed, maximum allowable power dissipation is reduced.
2. Maximum power dissipation varies depending on the package. Be sure to use a case which will keep warming within the limits shown in the table below.

Allowable power dissipation (W) and maximum temperature rising

Temp.	+25°C	+55°C	+85°C	+125°C
Case				
P case (2012)	0.025	0.022	0.020	0.010
Max. Temp Rise [°C]	5	5	5	2



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(5) Impedance frequency characteristics

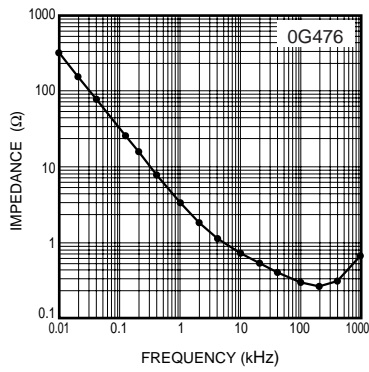


Fig.5

(6) ESR frequency characteristics

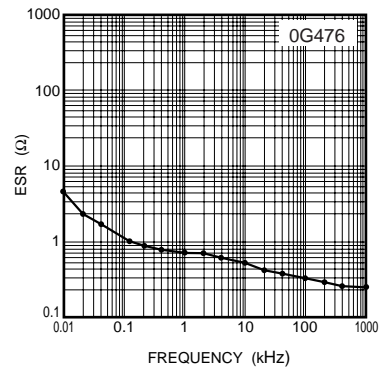


Fig.6

(7) Temperature characteristics

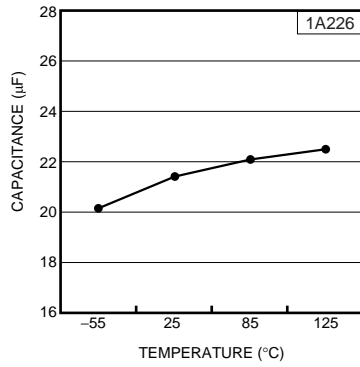


Fig.7

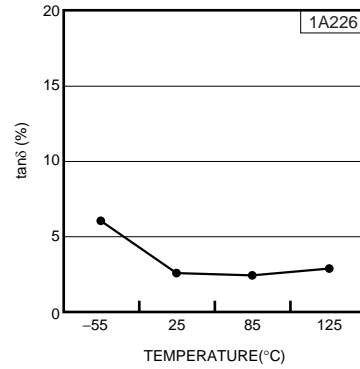


Fig.8

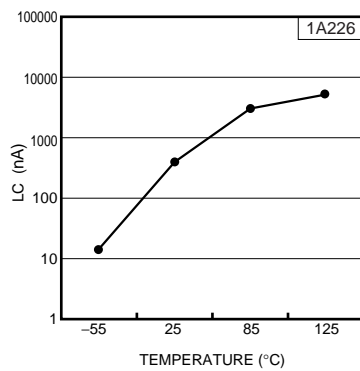


Fig.9

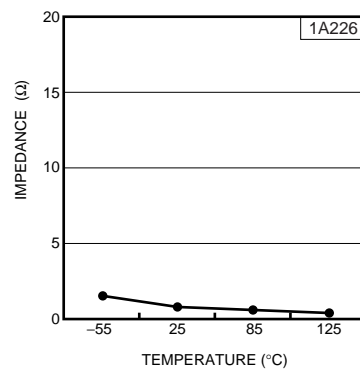


Fig.10